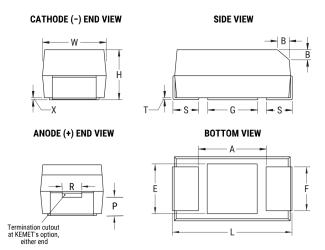


T493D336J010BT6110

T493 HRA, Tantalum, MnO2 Tantalum, HRA, 33 uF, 5%, 10 VDC, SMD, MnO2, Molded, High Reliability, B (0.1%/1000 Hrs), 800 mOhms, 7343, Height Max = 3.1mm



Click here for the 3D model.

Dimensions	
Footprint	7343
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
Н	2.8mm +/-0.3mm
Т	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
A	3.8mm MIN
В	0.5mm +/-0.15mm
Е	3.5mm REF
G	3.5mm REF
Р	O.5mm MIN
R	1mm REF
X	0.1mm +/-0.1mm

Packaging Specifications		
Packaging	T&R, 178mm	
Packaging Quantity	500	

General Information		
Series	T493 HRA	
Dielectric	MnO2 Tantalum	
Style	SMD Chip	
Description	SMD, MnO2, Molded, High Reliability	
Features	High Reliability	
RoHS	Yes	
Termination	Tin	
AEC-Q200	No	
Component Weight	412.33 mg	
Notes	P and R dimensions represents the minimum solderable area of the termination surface entirely below cutout (if one is present).	

Specifications		
Capacitance	33 uF	
Capacitance Tolerance	5%	
Voltage DC	10 VDC (85C), 6.7 VDC (125C)	
Temperature Range	-55/+125°C	
Rated Temperature	85°C	
Dissipation Factor	6% 120Hz 25C	
Failure Rate	B (0.1%/1000 Hrs)	
Resistance	0.8 Ohms (100kHz 25C)	
Ripple Current	433 mA (rms, 100kHz 25C)	
Leakage Current	3.3 uA (5min 25°C)	
Testing and Reliability	Standard Testing Only	

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